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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Noboru Ichinose, et al.

Serial No.: 10/567,369

Group Art Unit: 2814

Filed: May 15, 2006

Examiner: Sarah Kate Salerno

For: SEMICONDUCTOR LAYER WITH A Ga_2O_3 SYSTEM

Honorable Commissioner of Patents
Alexandria, VA 22313 – 1450

STATEMENT OF SUBSTANCE OF THE INTERVIEW

Sir:

Applicants thank the Examiner for the Personal Interview of October 7, 2010.

The Examiner agreed that the Amendment and verified translation of the priority document that were filed on September 30, 2010 overcome the prior art of record. The Examiner indicated that she would reconsider her position in the next office communication.

Respectfully Submitted,

Date: 10/13/10

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